# NSN 5961-00-188-7050

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Inclosure Material:

Metal

**Overall Length:** 

0.500 inches

## **Overall Diameter:**

0.765 inches

## **Mounting Facility Quantity:**

1

### **Internal Configuration:**

Junction contact

### **Mounting Method:**

Threaded stud

### **Overall Width Across Flats:**

Between 0.855 inches and 0.875 inches

#### **Thread Size:**

0.312 inches

### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, collector-to-base, emitter open and 100.0 breakdown voltage, collector-to-emitter, base open

## **Current Rating Per Characteristic:**

30.00 amperes source cutoff current

## Power Rating Per Characteristic:

200.0 watts small-signal input power, common-collector

### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

### **Special Features:**

Junction pattern arrangement: npn

### **Thread Series Designator:**

Unf

## Terminal Type And Quantity:

3 tab, solder lug

Shelf Life:

N/a

## Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

Fiig:

A110a0